

Voltage regulator diodes**BZW03 series****FEATURES**

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Zener working voltage range: 7.5 to 270 V for 38 types
- Transient suppressor stand-off voltage range: 6.2 to 430 V for 45 types
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed

construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

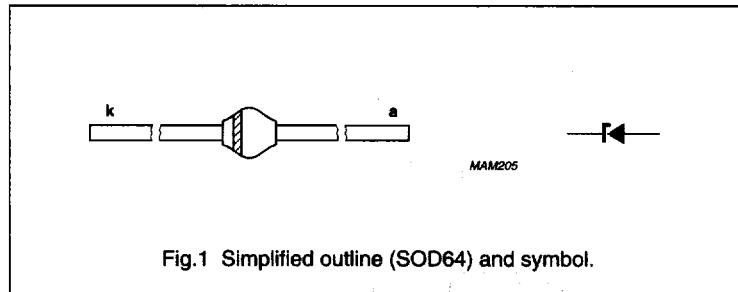


Fig.1 Simplified outline (SOD64) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
P_{tot}	total power dissipation	$T_{tp} = 25^\circ\text{C}$; lead length 10 mm; see Fig.2	–	6.00	W
		$T_{amb} = 45^\circ\text{C}$; see Fig.2; PCB mounted (see Fig.6)	–	1.75	W
P_{ZRM}	repetitive peak reverse power dissipation		–	20	W
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu\text{s}$; square pulse; $T_j = 25^\circ\text{C}$ prior to surge; see Fig.3	–	1000	W
P_{RSM}	non-repetitive peak reverse power dissipation	$10/1000 \mu\text{s}$ exponential pulse (see Fig.7); $T_j = 25^\circ\text{C}$ prior to surge; see Fig.4	–	500	W
T_{stg}	storage temperature		-65	+175	°C
T_j	junction temperature		-65	+175	°C

Voltage regulator diodes

BZW03 series

ELECTRICAL CHARACTERISTICS

Total series

 $T_j = 25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	forward voltage	$I_F = 1 \text{ A}$; see Fig.5	1.2	V

Per type when used as voltage regulator diodes

 $T_j = 25^\circ\text{C}$ unless otherwise specified.

TYPE No. SUFFIX (1)	WORKING VOLTAGE			DIFFERENTIAL RESISTANCE		TEMPERATURE COEFFICIENT		TEST CURRENT	REVERSE CURRENT AT REVERSE VOLTAGE		
	$V_Z (\text{V})$ at I_Z			$r_{\text{diff}} (\Omega)$ at I_Z		$S_Z (\%/\text{K})$ at I_Z			$I_R (\mu\text{A})$	at $V_R (\text{V})$	
	MIN.	NOM.	MAX.	TYP.	MAX.	MIN.	MAX.		MAX.		
C7V5	7.0	7.5	7.9	0.7	1.5	0.00	0.07	175	1500	5.6	
C8V2	7.7	8.2	8.7	0.8	1.5	0.03	0.08	150	1200	6.2	
C9V1	8.5	9.1	9.6	0.9	2.0	0.03	0.08	150	40	6.8	
C10	9.4	10	10.6	1.0	2.0	0.05	0.09	125	20	7.5	
C11	10.4	11	11.6	1.1	2.5	0.05	0.10	125	15	8.2	
C12	11.4	12	12.7	1.1	2.5	0.05	0.10	100	10	9.1	
C13	12.4	13	14.1	1.2	2.5	0.05	0.10	100	4	10	
C15	13.8	15	15.6	1.2	2.5	0.05	0.10	75	2	11	
C16	15.3	16	17.1	1.3	2.5	0.06	0.11	75	2	12	
C18	16.8	18	19.1	1.3	2.5	0.06	0.11	65	2	13	
C20	18.8	20	21.2	1.5	3.0	0.06	0.11	65	2	15	
C22	20.8	22	23.3	1.6	3.5	0.06	0.11	50	2	16	
C24	22.8	24	25.6	1.8	3.5	0.06	0.11	50	2	18	
C27	25.1	27	28.9	2.5	5	0.06	0.11	50	2	20	
C30	28	30	32	4	8	0.06	0.11	40	2	22	
C33	31	33	35	5	10	0.06	0.11	40	2	24	
C36	34	36	38	6	11	0.06	0.11	30	2	27	
C39	37	39	41	7	14	0.06	0.11	30	2	30	
C43	40	43	46	10	20	0.07	0.12	30	2	33	
C47	44	47	50	12	25	0.07	0.12	25	2	36	
C51	48	51	54	14	27	0.07	0.12	25	2	39	
C56	52	56	60	18	35	0.07	0.12	20	2	43	
C62	58	62	66	20	42	0.08	0.13	20	2	47	
C68	64	68	72	22	44	0.08	0.13	20	2	51	
C75	70	75	79	25	45	0.08	0.13	20	2	56	
C82	77	82	87	30	65	0.08	0.13	15	2	62	
C91	85	91	96	40	75	0.09	0.13	15	2	68	

Voltage regulator diodes

BZW03 series

TYPE No. SUFFIX (1)	WORKING VOLTAGE			DIFFERENTIAL RESISTANCE		TEMPERATURE COEFFICIENT		TEST CURRENT	REVERSE CURRENT at REVERSE VOLTAGE		
	V_Z (V) at I_Z			r_{dif} (Ω) at I_Z		S_Z (%/K) at I_Z			I_Z (mA)	at V_R (V)	
	MIN.	NOM.	MAX.	TYP.	MAX.	MIN.	MAX.		MAX.		
C100	94	100	106	45	90	0.09	0.13	12	2	75	
C110	104	110	116	65	125	0.09	0.13	12	2	82	
C120	114	120	127	90	170	0.09	0.13	10	2	91	
C130	124	130	141	100	190	0.09	0.13	10	2	100	
C150	138	150	156	150	330	0.09	0.13	8	2	110	
C160	153	160	171	180	350	0.09	0.13	8	2	120	
C180	168	180	191	210	430	0.09	0.13	5	2	130	
C200	188	200	212	250	500	0.09	0.13	5	2	150	
C220	208	220	233	350	700	0.09	0.13	5	2	160	
C240	228	240	256	450	900	0.09	0.13	5	2	180	
C270	251	270	289	600	1200	0.09	0.13	5	2	200	

Note

1. To complete the type number the suffix is added to the basic type number, e.g. BZW03-C100.

Voltage regulator diodes

BZW03 series

Per type when used as transient suppressor diodes

 $T_j = 25^\circ\text{C}$ unless otherwise specified.

TYPE NUMBER	REVERSE BREAKDOWN VOLTAGE	TEMPERATURE COEFFICIENT		TEST CURRENT I_{test} (mA)	CLAMPING VOLTAGE		REVERSE CURRENT at STAND-OFF VOLTAGE		
	$V_{(BR)R}$ (V) at I_{test}	S_z (%/K) at I_{test}			$V_{(CL)R}$ (V) MAX.	at I_{RSM} (A) note 1	I_R (mA) MAX.	V_R (V)	
		MIN.	MAX.						
BZW03-C7V5	7.0	0.00	0.07	175	11.3	44.2	3000	6.2	
BZW03-C8V2	7.7	0.03	0.08	150	12.3	40.6	2400	6.8	
BZW03-C9V1	8.5	0.03	0.08	150	13.3	37.6	100	7.5	
BZW03-C10	9.4	0.05	0.09	125	14.8	34.0	40	8.2	
BZW03-C11	10.4	0.05	0.10	125	15.7	31.8	30	9.1	
BZW03-C12	11.4	0.05	0.10	100	17.0	29.4	20	10	
BZW03-C13	12.4	0.05	0.10	100	18.9	26.4	10	11	
BZW03-C15	13.8	0.05	0.10	75	20.9	23.9	10	12	
BZW03-C16	15.3	0.06	0.11	75	22.9	21.8	10	13	
BZW03-C18	16.8	0.06	0.11	65	25.6	19.5	10	15	
BZW03-C20	18.8	0.06	0.11	65	28.4	17.6	10	16	
BZW03-C22	20.8	0.06	0.11	50	31.0	16.1	10	18	
BZW03-C24	22.8	0.06	0.11	50	33.8	14.8	10	20	
BZW03-C27	25.1	0.06	0.11	50	38.1	13.1	10	22	
BZW03-C30	28	0.06	0.11	40	42.2	11.8	10	24	
BZW03-C33	31	0.06	0.11	40	46.2	10.8	10	27	
BZW03-C36	34	0.06	0.11	30	50.1	10.0	10	30	
BZW03-C39	37	0.06	0.11	30	54.1	9.2	10	33	
BZW03-C43	40	0.07	0.12	30	60.7	8.2	10	36	
BZW03-C47	44	0.07	0.12	25	65.5	7.6	10	39	
BZW03-C51	48	0.07	0.12	25	70.8	7.0	10	43	
BZW03-C56	52	0.07	0.12	20	78.6	6.3	10	47	
BZW03-C62	58	0.08	0.13	20	86.5	5.8	10	51	
BZW03-C68	64	0.08	0.13	20	94.4	5.3	10	56	
BZW03-C75	70	0.08	0.13	20	103.5	4.8	10	62	
BZW03-C82	77	0.08	0.13	15	114.0	4.3	10	68	
BZW03-C91	85	0.09	0.13	15	126	3.9	10	75	
BZW03-C100	94	0.09	0.13	12	139	3.6	10	82	
BZW03-C110	104	0.09	0.13	12	152	3.3	10	91	
BZW03-C120	114	0.09	0.13	10	167	3.0	10	100	
BZW03-C130	124	0.09	0.13	10	185	2.7	10	110	
BZW03-C150	138	0.09	0.13	8	204	2.4	10	120	
BZW03-C160	153	0.09	0.13	8	224	2.2	10	130	

Voltage regulator diodes

BZW03 series

TYPE NUMBER	REVERSE BREAKDOWN VOLTAGE	TEMPERATURE COEFFICIENT		TEST CURRENT	CLAMPING VOLTAGE		REVERSE CURRENT at STAND-OFF VOLTAGE	
	$V_{(BR)R}$ (V) at I_{test}	S_z (%/K) at I_{test}		I_{test} (mA)	$V_{(CL)R}$ (V)	at I_{RSM} (A) note 1	I_R (μ A)	V_R (V)
		MIN.	MIN.		MAX.		MAX.	
BZW03-C180	168	0.09	0.13	5	249	2.0	10	150
BZW03-C200	188	0.09	0.13	5	276	1.8	10	160
BZW03-C220	208	0.09	0.13	5	305	1.6	10	180
BZW03-C240	228	0.09	0.13	5	336	1.5	10	200
BZW03-C270	251	0.09	0.13	5	380	1.3	10	220
BZW03-C300	280	0.09	0.13	5	419	1.2	10	240
BZW03-C330	310	0.09	0.13	5	459	1.1	10	270
BZW03-C360	340	0.09	0.13	5	498	1.0	10	300
BZW03-C390	370	0.09	0.13	5	537	0.93	10	330
BZW03-C430	400	0.09	0.13	5	603	0.83	10	360
BZW03-C470	440	0.09	0.13	5	655	0.76	10	390
BZW03-C510	480	0.09	0.13	5	707	0.71	10	430

Note

1. Non-repetitive peak reverse current in accordance with "IEC 60-1, Section 8" (10/1000 μ s pulse); see Fig.7.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\ -tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th\ j\ -a}$	thermal resistance from junction to ambient	note 1	75	K/W

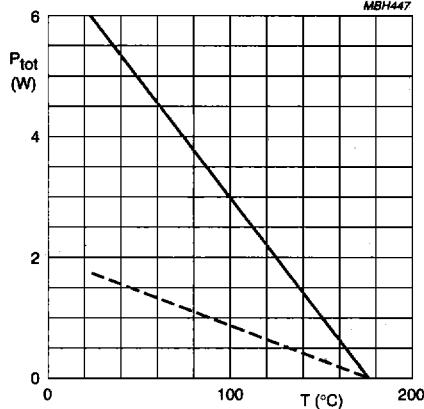
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer \geq 40 μ m, see Fig.6.
For more information please refer to the 'General Part of Handbook SC01'.

Voltage regulator diodes

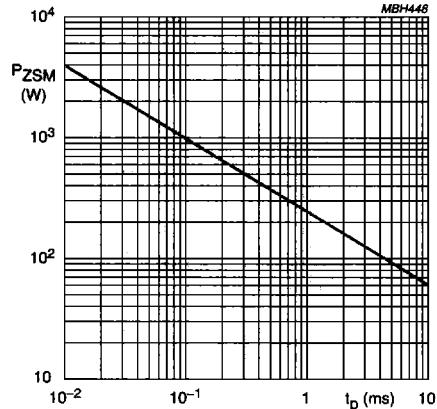
BZW03 series

GRAPHICAL DATA



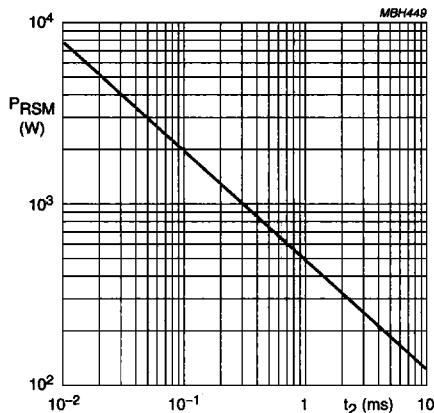
Solid line: tie-point temperature; lead length = 10 mm.
Dotted line: ambient temperature; device mounted as shown in Fig.6.

Fig.2 Maximum total power dissipation as a function of temperature.



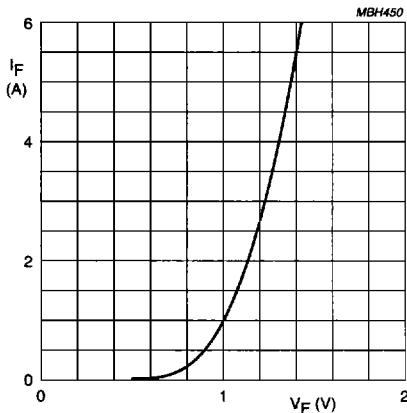
T_j = 25 °C prior to surge.

Fig.3 Maximum non-repetitive peak reverse power dissipation as a function of pulse duration (square pulse).



T_j = 25 °C prior to surge.
For definition of exponential pulse see Fig.7.

Fig.4 Maximum non-repetitive peak reverse power dissipation as a function of pulse duration (exponential pulse).

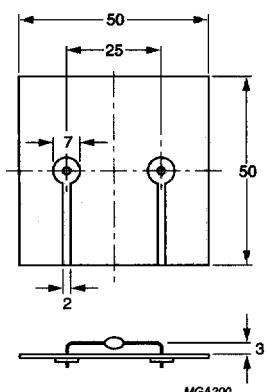


T_j = 25 °C.

Fig.5 Forward current as a function of forward voltage; typical values.

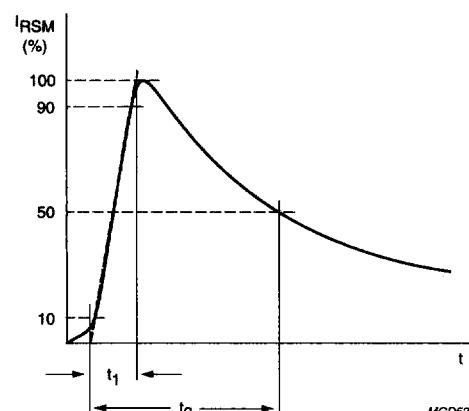
Voltage regulator diodes

BZW03 series



Dimensions in mm.

Fig.6 Device mounted on a printed-circuit board.



In accordance with "IEC 60-1, Section 8".

$t_1 = 10 \mu\text{s}$.

$t_2 = 1000 \mu\text{s}$.

Fig.7 Non-repetitive peak reverse current pulse definition.